

Strongly interacting σ -electrons and MgB_2 superconductivity

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Abstract

$\text{MgB}(p^{n_\sigma} p^{n_\pi})_2$ is classified as a system with strongly interacting σ -electrons and non-correlated π -electrons of boron ions. The kinematic and Coulomb interaction V between the orbitally degenerated σ -electrons provide the superconducting state with an anisotropic gap of s^* -wave symmetry. The critical temperature T_c has a non-monotonic dependence on the distance r between the centers of gravity of σ - and π -bands. MgB_2 corresponds to $r = 0.085$ eV and $V = 0.45$ eV in our model with flat bands. The derived superconducting density of electronic states is in good agreement with available experimental and theoretical data. The possibilities for increasing T_c are discussed.

Keywords: A. Superconductors; C. Crystal structure and symmetry; D. Electronic band structure; D. Electron correlations

The unprecedented discovery of superconductivity in the simple binary material MgB_2 [1] has opened up new avenues to attack the problem of maximizing T_c and the symmetry of the order parameter. In the present paper we present a model to explain the superconducting state in MgB_2 which is based on the correlated σ - and the non-correlated π -band. The negatively charged boron layers and the positively charged magnesium layers provide a lowering of the π -band with respect to the σ -band, as pointed out in Ref. [2] and which was also noticed first in band calculations [3, 4, 5]. Tight-binding estimates show that the bonding σ -band, close to the Fermi level, is doubly degenerate (it has E -symmetry [6, 7]). The quasi-2D σ -electrons are more localized than the 3D π -electrons. This leads to an enhancement of the on-site electron correlations in the system of degenerated σ -electrons. They are taken to be infinite, while the somewhat weaker intersite Coulomb interactions and electron-phonon interactions simply shift the on-site electron energies. After carrying out a fermion mapping to X -operators the Hamiltonian becomes:

$$\begin{aligned}
 H = & \sum_{p,s} t^{(\sigma)}(p) X^{so}(p) X^{os}(p) + V \sum_{\langle i,j \rangle} n_\sigma(i) n_\sigma(j) - r \sum_i n_\pi(i) + \\
 & + \sum_{p,s} \varepsilon_0^{(\pi)}(p) [\pi_s^+(p) \pi_s(p) + H.c.] - \mu \sum_i [n_\sigma(i) + n_\pi(i)]. \quad (1)
 \end{aligned}$$

It is written in the usual notations, where the non-diagonal X -operators describe the on-site transitions of correlated σ -electrons between the one-particle ground states (with spin projection $s = \pm$) and the empty polar electronic states (0) of the boron sites and μ is the chemical potential. The wide π -band is shifted with respect to the σ -band by an energy r . This parameter comprises the mean-field π -electron interactions, the electron-phonon interactions (e.g. the contribution of the strong coupling of E_{2g} -phonons with the σ -electrons [8]) *etc.* We included in Eq. (1) also the nearest neighbour Coulomb repulsion V of σ -electrons, which is essential for the low density of hole-carriers present in MgB_2 . The mutual hopping between σ - and π -electrons is assumed to be negligible due to the characteristic space symmetry of the orbitals involved. A schematic view of our model is presented in Fig. 1. The diagonal X -operators ($X \equiv X^{\cdot}$) conform to the completeness relation, $X^0 + 4X^s = 1$, and their thermodynamic averages ($\langle X^0 \rangle$, $\langle X^s \rangle$) are the Boltzmann populations of the energy levels of the unperturbed on-site Hamiltonian in (1). Due to the orbital and spin degeneracy the σ -electrons occupy their one-particle ground state with density $n_\sigma = 4 \langle X^s \rangle$ per boron site. The correlation factor for the degenerated σ -electrons is

$$f = \langle X^0 + X^s \rangle = 1 - 3 \langle X^s \rangle = 1 - \frac{3}{4} n_\sigma, \quad (2)$$

and it plays an important role in all arithmetics starting from their unperturbed (zeroth order) Green's function, $D_\sigma^{(0)}(\omega) = f / (-i\omega_n - \mu)$, whereas for π -electrons $D_\pi^{(0)}(\omega) = 1 / (-i\omega_n - \mu - r)$. Note that for the conventional Hubbard model the correlation factor in the paramagnetic phase is $1 - n/2$ (see [9] and Refs. therein). The energy dispersion of both bands, $\xi(p) = ft(p) - \mu$ and $\varepsilon(p) = \varepsilon_0(p) - r - \mu$, are governed by zeros of the inverse Green's function

$$D^{-1}(\omega, p) = \text{diag} \{ D_\sigma^{-1}(\omega, p); D_\pi^{-1}(\omega, p) \} = \text{diag} \left\{ \frac{-i\omega_n + \xi(p)}{f}; -i\omega_n + \varepsilon(p) \right\},$$

which follows from the Dyson equation

$$D^{-1}(\omega, p) = D^{(0)-1}(\omega) + \hat{t}(p),$$

to first order with respect to the tunneling matrix $\hat{t}(p) = \text{diag}\{t(p); \varepsilon_0(p)\}$, where $\text{diag}\{A; B\} = \begin{pmatrix} A & 0 \\ 0 & B \end{pmatrix}$.

The chemical potential μ for the $\text{MgB}_2 = \text{Mg}^{++}\text{B}^-(p^2)_2 = \text{Mg}^{++}\text{B}^-(p^{n_\sigma}p^{n_\pi})_2$ -system (Eq. (1)) obeys the equation for the total electron density per boron site

$$n_\sigma + n_\pi = 2, \quad (3)$$

with the partial electron densities given by

$$n_{\sigma,\pi} = 2T \sum_{n,p} e^{i\omega\delta} D_{\sigma,\pi}(\omega, p) \equiv n_{\sigma,\pi}(r, \mu). \quad (4)$$

The electron densities, Eq. (4), comply with the requirements $0 < n_\sigma < 1$ (due to the correlation factor, Eq. (2), providing the quarter-fold narrowing of the

degenerate σ -band) and $0 < n_\pi < 2$. For any energy difference r between the σ - and π -bands the chemical potential μ has to be such that Eq. (3) for the band fillings is satisfied.

From the system of Eqs. (3, 4) for a flat density of electronic states (DOS hereafter) $\rho_{\sigma,\pi}(\varepsilon) = (1/2w_{1,2}) \theta(w_{1,2}^2 - \varepsilon^2)$ with half-bandwidths w_1 and w_2 for σ - and π -electrons, respectively and $\theta(x)$ is the theta function) we derive the chemical potential of the $A^{2+}B(p^{n_\sigma}p^{n_\pi})_2$ systems as

$$\mu = \frac{w_2 - 5r}{5w_1 + 4w_2} w_1. \quad (5)$$

The non-correlated π -electrons play the role of a reservoir for the σ -electrons. In the energy dispersion $\xi(p)$ for the σ -electrons, the correlation factor, Eq. (2), can be expressed also via the electron structure parameters w_1, w_2 and r as $f = (2w_1 + w_2 + 3r) / (5w_1 + 4w_2)$.

The anomalous self-energy for the σ -electrons (Fig. 2) is written self-consistently as

$$\check{\Sigma}(p) = T \sum_{n,q} \Gamma_0(p, q) \frac{\check{\Sigma}(q)}{\omega_n^2 + \xi^2(q) + \check{\Sigma}(q)}, \quad (6)$$

where the vertex Γ_0 is determined by the amplitudes of the kinematic and Coulomb interactions such that $\Gamma_0(p, q) = -2t_q + V(p - q)$. We do not include the other kinematic vertices in Γ_0 essential for a comparative analysis of the anisotropic singlet and for triplet pairings and the energy band renormalization at a moderate concentration of carriers [9]. In momentum space the Coulomb repulsion between the nearest neighbours (Eq. (1)) reflects the tight-binding symmetry of the boron honeycomb lattice, $\sqrt{3 + 2 \left(\cos p_y + 2 \cos \frac{p_y}{2} \cos \frac{\sqrt{3}p_x}{2} \right)}$. Near the $\Gamma - A$ line of the Brillouin zone the Coulomb vertex can be factorized as

$$V(p - q) = 2\beta t(p) t(q),$$

where the parameter $\beta = V/6t^2$ expresses the Coulomb repulsion for the nearest σ -electrons and the energy dispersion is $t(p) = 3t \left(1 - \frac{p_x^2 + p_y^2}{12} \right)$. Putting the explicit form of the vertex Γ_0 in Eq. (6), and after summation over the Matsubara frequencies $\omega_n = (2n + 1)\pi T$ one obtains

$$\check{\Sigma}(p) = \sum_q t(q) (1 - \beta t(p)) \check{\Sigma}(q) \frac{\tanh \sqrt{\xi^2(q) + \check{\Sigma}^2(q)}/2T}{\sqrt{\xi^2(q) + \check{\Sigma}^2(q)}}. \quad (7)$$

The search for a solution in the form $\check{\Sigma}(p) = \Sigma_0 + t(p) \Sigma_1$ converts Eq. (7) for the superconducting critical temperature and the gap in $A^{2+}B_2^-$ to

$$1 = \sum_p t(p) (1 - \beta t(p)) \frac{\tanh \sqrt{\xi^2(p) + \Sigma^2(p)}/2T}{\sqrt{\xi^2(p) + \Sigma^2(p)}}, \quad (8)$$

with the gap function $\Sigma(p) = [1 - \beta t(p)] \Sigma_0$.

Equalizing the gap function in Eq. (8) to zero, one can derive analytically T_c in the logarithmic approximation for a flat DOS :

$$T_c = \frac{w_1}{5w_1 + 4w_2} \sqrt{(w_1 + w_2 - r)(w_1 + 4r)} \exp\left(-\frac{1}{\lambda}\right),$$

$$\lambda = \frac{(5w_1 + 4w_2)(3 + 5\beta w_1)}{(2w_1 + w_2 + 3r)^3} (w_2 - 5r) \left[r - \frac{\beta w_1 w_2 - 2w_1 - w_2}{3 + 5\beta w_1} \right]. \quad (9)$$

Under the prefactor in the square root the restrictions for an energy shift r guarantee the assumed volume of the correlated σ -band, namely $n_\sigma \geq 0$ ($r \leq w_1 + w_2$) and $n_\sigma \leq 1$ ($r \geq -w_1/4 = -t$). $T_c(r)$ is plotted in Fig. 3 for different values of the parameter β , reflecting the suppression of superconductivity with an increase of the Coulomb repulsion. The critical temperature T_c has a non-monotonic dependence on the mutual position r of the σ - and π -bands. The MgB₂ case, $T_c = 40$ K, corresponds to $r = 0.085$ eV and a dimensionless value $\beta w_1 = 8 \text{ V}/3w_1$.

The superconducting gap equation follows from Eq. (8) taken for $T=0$

$$1 = \int \rho_\sigma(\varepsilon) \varepsilon (1 - \beta \varepsilon) \frac{d\varepsilon}{\sqrt{\xi^2(\varepsilon) + \Sigma_0^2(1 - \beta \varepsilon)^2}}. \quad (10)$$

It defines the anisotropic superconducting order parameter of s^* -wave symmetry. In contrast to the isotropic s -wave gap, the superconducting gap does not coincide with the amplitude Σ_0 of the gap function and it should be defined by the minimal square root in Eq. (10).

The near-cylindrical hole-like σ -Fermi surfaces in MgB₂ gives room to calculate the superconducting DOS $\rho(E) = \sum_p \delta(E - \sqrt{\varepsilon^2(p) + \Sigma^2(p)})$, where the gap function (cf. Eq. (10)) is

$$\Sigma = \Sigma_0(1 - \beta t(p)) = b(1 + a \cos^2 \vartheta), \quad (11)$$

where $a = \beta w_1 / (12(1 - \beta w_1))$, $b = \Sigma_0(1 - \beta w_1)$ and ϑ is the azimuthal angle. Then the superconducting DOS normalized with respect to the normal DOS is

$$\frac{\rho(E)}{\rho_0(E)} = E \int_0^1 \frac{dz}{\sqrt{E^2 - b^2(1 + az^2)^2}}. \quad (12)$$

For a Coulomb repulsion such that $\beta w_1 < 1$ the parameter satisfies $a > 0$ and the superconducting DOS becomes

$$\frac{\rho(b < E < (1 + a)b)}{\rho_0(E)} = \sqrt{\frac{E}{2ab}} K(q),$$

$$\frac{\rho(E > (1 + a)b)}{\rho_0(E)} = \sqrt{\frac{E}{2ab}} F\left(\sin^{-1} \sqrt{\frac{ab}{(E + (1 + a)b)q^2}}; q\right), \quad (13)$$

which is expressed in terms of the complete and incomplete elliptic integrals K and F , respectively with modulus $q = \sqrt{(E - b)/2E}$. The DOS (13) has cusps at $E = \pm(1 + a)b$. A similar result was obtained in Ref. [10] for a non-specified

parameter $a > 0$. In our case the parameter a is controlled by the in-plane Coulomb repulsion V as the authors of Ref. [6] noted. At $\beta w_1 = 0.92$ the DOS of Eq. (13) (see Fig. 4, inset) reproduces Fig. 1(b) of Ref. [10].

But for our case of an enhanced Coulomb repulsion $\beta w_1 > 1$, we have to take the parameter $a < 0$ in the gap function (11) and the superconducting DOS (Fig. 4) is then given by

$$\begin{aligned} \frac{\rho((1-|a|)b < E < b)}{\rho_0(E)} &= \frac{E}{\sqrt{(E+b)|a|b}} F\left(\sin^{-1} \frac{1}{q}; \sqrt{\frac{2E}{E+b}}\right), \\ \frac{\rho(E > b)}{\rho_0(E)} &= \sqrt{\frac{E}{2|a|b}} F\left(\sin^{-1} q; \sqrt{\frac{E+b}{2E}}\right). \end{aligned} \quad (14)$$

For our $a < 0$ case the superconducting DOS (14) contains two logarithmic divergencies at $E = \pm b$ and a gap in the energy range $|E| < (1-|a|)b$. The "gap" ratio is $1/(1-|a|)$.

Measurements on MgB_2 with scanning tunneling spectroscopy [11, 12] and with high-resolution photo-emission spectroscopy [13] revealed the presence of these two gap sizes. From the ratio 3.3 between the two gaps in Ref. [11] we can extract the parameters $|a| \approx 2/3$ and $\beta w_1 \approx 1.14$ (see Eq. (11)), whereas from data of Ref. [12] one can derive $\beta w_1 = 1.21$. A value $\beta w_1 = 1.14$ can be estimated from Ref. [13]. Point-contact spectroscopy [14] shows gaps at 2.8 and 7 meV, from which we estimate a Coulomb repulsion parameter $\beta w_1 = 1.16$. The recent study of energy gaps in superconducting MgB_2 by specific-heat measurements revealed "gaps" at 2.0 meV and 7.3 meV [15] for which $\beta w_1 = 1.13$, and a gap ratio $3 - 2.2$ [16], for which $\beta w_1 = 1.14 - 1.15$. Measurements of the specific heat of Mg^{11}B_2 also give evidence for a second energy gap [17]. It is worth noticing that earlier Raman measurements [18] have revealed the presence not only of the discussed peak at 110 cm^{-1} , but also of an asymmetric peak at $65 - 60 \text{ cm}^{-1}$ (see Figs. 1 and 2 in Ref. [18]). These results correspond to a gap ratio $0.6 - 0.54$, from which we estimate $|a| = 0.41 - 0.45$ (cf. Eq. (14)) and a Coulomb parameter $\beta w_1 = 1.25 - 1.22$ (Eq. (11)). Later Raman measurements [19] established pronounced peaks, corresponding with gaps at 100 cm^{-1} and 44 cm^{-1} . From these data one can extract $a = -0.56$ and $\beta w_1 = 1.18$. At $\beta w_1 = 1$ we have gapless like superconductivity. In this case the superconducting DOS is linear with respect to the energy near the nodes of the superconducting order parameter. Then the superconducting specific heat $C_e \sim T^2$ and the NMR boron relaxation rate $\sim T^3$ at low temperatures (for BEDT-TTF organic salts this is shown in Ref. [20]). From this point of view it is interesting that the data of Ref. [21] shows a $C_e \sim T^2$ behaviour and a deviation from the exponential BCS behaviour in $T_1^{-1}(T)$ of ^{11}B [22] visualized in MgB_2 .

In summary, we have analyzed the superconducting properties of the material MgB_2 within the framework of a correlated model (1). The existing electron-phonon and non-phonon approaches to the superconducting mechanism in MgB_2 can be separated in two groups: one pays attention to the σ -electrons and the other to the π -electron subsystem. We have taken into account both the correlated σ - and noncorrelated π -electrons. Analysis of our results leads to the conclusion that superconductivity occurs in the subsystem of σ -electrons with degenerate narrow energy bands whereas the wide-band π -electrons play

the role of a reservoir. Superconductivity is driven by a non-phonon kinematic interaction in the σ -band. A lot of evidences in favour of two different superconducting gaps can be explained by anisotropic superconductivity with an order parameter of s^* -wave symmetry, induced by the in-plane Coulomb repulsion. For an enhanced interboron Coulomb repulsion ($\beta w_1 > 1$) the logarithmic divergencies in the superconducting DOS (Eq. 14, Fig. 4) are manifested by a second gap in the experiments. The kinematic mechanism of superconductivity for correlated electrons was first proposed for high- T_c -cuprates ([23], see [9] and Refs. therein) as a non-phonon mechanism with correlated hopping ([24], and Refs. therein). In Ref. [25] it was shown that in the strongly correlated limiting case the kinematic mechanism reproduces the result of hole dressed superconductivity. In our approach the electron-phonon coupling is hidden in the parameter r . Therefore the pressure and isotope effects can be explained by the dependence of $r(\omega)$ on the phonon modes. From the non-monotonic T_c dependence on r it follows that the MgB_2 material is in the underdoped regime (around $r \gtrsim -w_1/4$). For a fictitious system A^{2+}B_2 , where the two electrons are contributed by atom A, the superconducting critical temperature increases with an r increase. A pressure increase lowers the σ -band with an r decrease resulting in a negative pressure derivative of T_c in agreement with experiment [26]. The bell shaped curve $T_c(r)$, with the MgB_2 position in the underdoped regime, shows a possibility to reach higher T_c 's in diboride materials such as $\text{A}^{2+}\text{B}_2^-$ with an AlB_2 crystal structure. We suggest the synthesis of materials with increased r -values (e.g. with "negative chemical pressure") and optimized smaller interatomic B-B distances in the honeycomb plane.

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Figure captions

Fig. 1 A schematic view of the energy band diagram. The degenerate σ -electrons are represented by a lower correlated band.

Fig. 2 The anomalous self-energy $\Sigma^\vee(p)$ for σ -electrons. The solid line is an anomalous Green's function (cf. Eq. (6)).

Fig. 3 The non-monotonic dependence of $T_c(r)$ at different magnitudes of the Coulomb repulsion (parameter βw_1). Here $w_2/w_1 = 8$. MgB₂ is marked in the inset with a solid circle positioned at $r = 0.085$ eV and $\beta w_1 = 1.2$ for $w_1 = 1$ eV and $w_2 = 8$ eV.

Fig. 4 The superconducting DOS, normalized with respect to the normal DOS, for the Coulomb parameter range $\beta w_1 > 1$. At $\beta w_1 = 0.92$, the Maki result [10] is reproduced (inset) (cf. Eq. (13)).

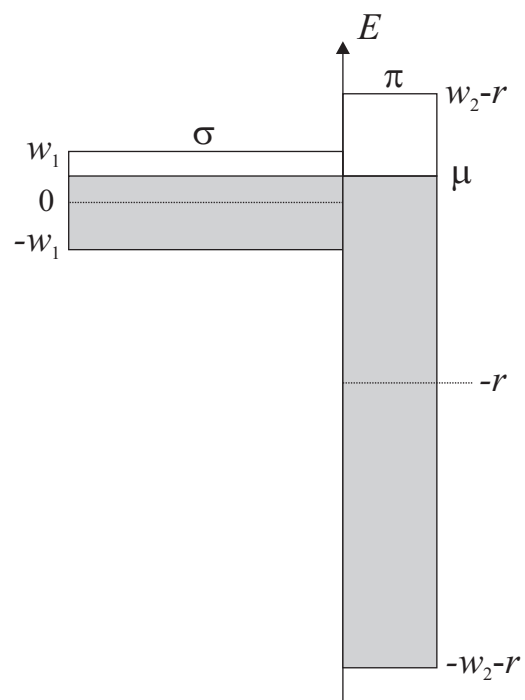


Fig. 1: Ivanov et al.

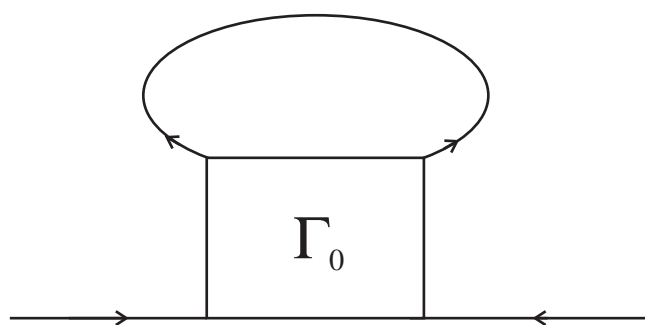


Fig. 2: Ivanov et al.

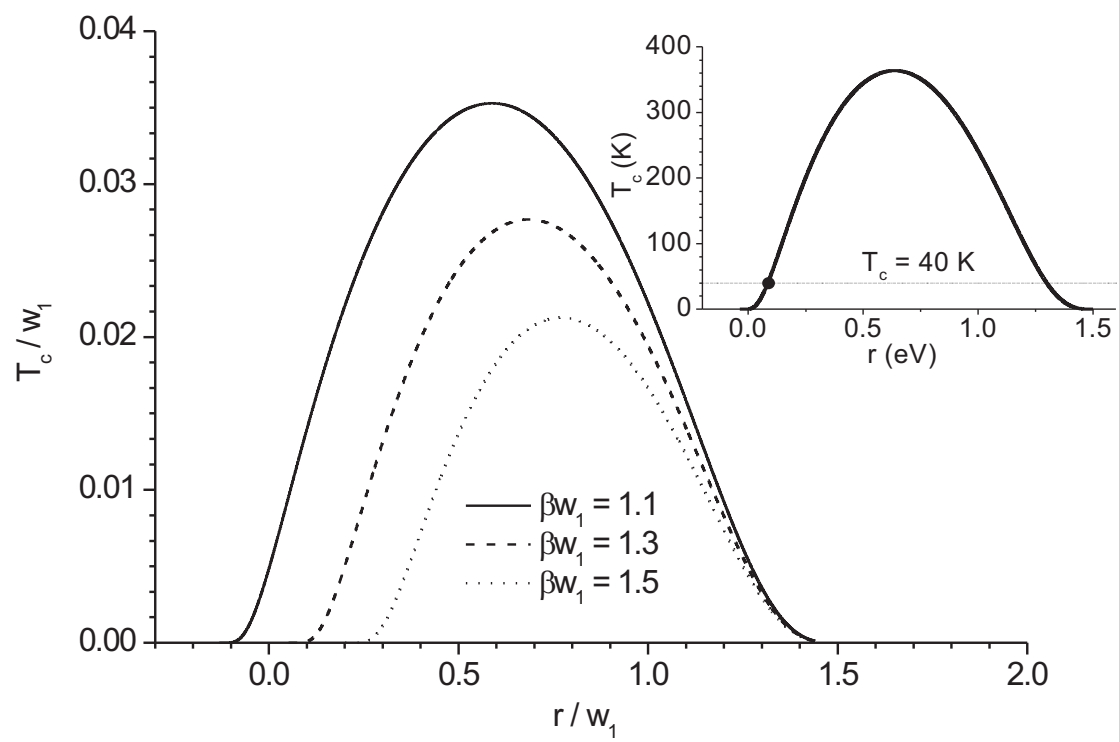


Fig. 3: Ivanov et al.

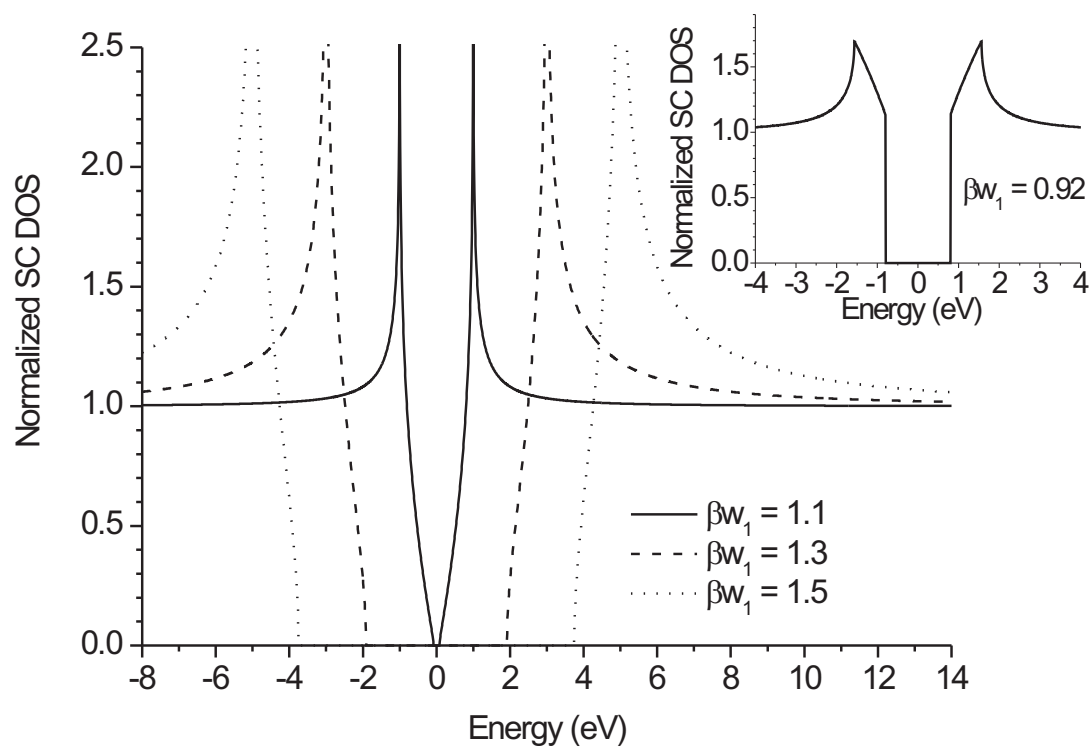


Fig. 4: Ivanov et al.